ESP32-WROOM-32E & ESP32-WROOM-32UE

Datasheet



About This Document

This document provides the specifications for the ESP32-WROOM-32E and ESP32-WROOM-32UE modules.

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1 Module Overview

1.1 Features

MCU

- ESP32-D0WD-V3 embedded, Xtensa[®] dual-core 32-bit LX6 microprocessor, up to 240 MHz
- 448 KB ROM for booting and core functions
- 520 KB SRAM for data and instructions
- 16 KB SRAM in RTC

Wi-Fi

- 802.11b/g/n
- Bit rate: 802.11n up to 150 Mbps
- A-MPDU and A-MSDU aggregation
- 0.4 μ s guard interval support
- Center frequency range of operating channel: 2412 ~ 2484 MHz

Bluetooth®

Bluetooth V4.2 BR/EDR and Bluetooth LE specification

- Class-1, class-2 and class-3 transmitter
- AFH
- CVSD and SBC

Hardware

- Interfaces: SD card, UART, SPI, SDIO, I²C, LED PWM, Motor PWM, I²S, IR, pulse counter, GPIO, capacitive touch sensor, ADC, DAC
- 40 MHz crystal oscillator
- 4 MB SPI flash
- Operating voltage/Power supply: 3.0 ~ 3.6 V
- Operating temperature range: -40 ~ 85 °C
- Dimensions: See Table 1

Certification

• Bluetooth certification: BQB

• RF certification: FCC/CE-RED/SRRC

• Green certification: REACH/RoHS

1.2 Description

ESP32-WROOM-32E and ESP32-WROOM-32UE are two powerful, generic Wi-Fi+BT+BLE MCU modules that target a wide variety of applications, ranging from low-power sensor networks to the most demanding tasks, such as voice encoding, music streaming and MP3 decoding.

ESP32-WROOM-32E comes with a PCB antenna, and ESP32-WROOM-32UE with an IPEX antenna. They both feature a 4 MB external SPI flash. **The information in this datasheet is applicable to both modules.**

The ordering information of the two modules is listed as follows:

Table 1: Ordering Information

Module	Chip embedded Flash Module dimensions (mm)		Module dimensions (mm)
ESP32-WROOM-32E (PCB)	E6033 D0MD //3	4 MB ¹	(18.00±0.15)×(25.50±0.15)×(3.10±0.15)
ESP32-WROOM-32UE (IPEX)			(18.00±0.15)×(19.20±0.15)×(3.20±0.15)

Notes:

- 1. The module with 8 MB flash or 16 MB flash is available for custom order.
- 2. For detailed ordering information, please see *Espressif Product Ordering Information*.
- 3. For dimensions of the IPEX connector, please see Chapter 7.3.

At the core of the module is the ESP32-D0WD-V3 chip*. The chip embedded is designed to be scalable and

adaptive. There are two CPU cores that can be individually controlled, and the CPU clock frequency is adjustable from 80 MHz to 240 MHz. The chip also has a low-power co-processor that can be used instead of the CPU to save power while performing tasks that do not require much computing power, such as monitoring of peripherals. ESP32 integrates a rich set of peripherals, ranging from capacitive touch sensors, Hall sensors, SD card interface, Ethernet, high-speed SPI, UART, I²S and I²C.

Note:

* For details on the part numbers of the ESP32 family of chips, please refer to the document ESP32 Datasheet.

The integration of Bluetooth[®], Bluetooth LE and Wi-Fi ensures that a wide range of applications can be targeted, and that the module is all-around: using Wi-Fi allows a large physical range and direct connection to the Internet through a Wi-Fi router, while using Bluetooth allows the user to conveniently connect to the phone or broadcast low energy beacons for its detection. The sleep current of the ESP32 chip is less than 5 μ A, making it suitable for battery powered and wearable electronics applications. The module supports a data rate of up to 150 Mbps, and 20 dBm output power at the antenna to ensure the widest physical range. As such the module does offer industry-leading specifications and the best performance for electronic integration, range, power consumption, and connectivity.

The operating system chosen for ESP32 is freeRTOS with LwIP; TLS 1.2 with hardware acceleration is built in as well. Secure (encrypted) over the air (OTA) upgrade is also supported, so that users can upgrade their products even after their release, at minimum cost and effort.

1.3 Applications

- Generic Low-power IoT Sensor Hub
- Generic Low-power IoT Data Loggers
- Cameras for Video Streaming
- Over-the-top (OTT) Devices
- Speech Recognition
- Image Recognition
- Mesh Network
- Home Automation

- Smart Building
- Industrial Automation
- Smart Agriculture
- Audio Applications
- Health Care Applications
- Wi-Fi-enabled Toys
- Wearable Electronics
- Retail & Catering Applications

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2 Block Diagram

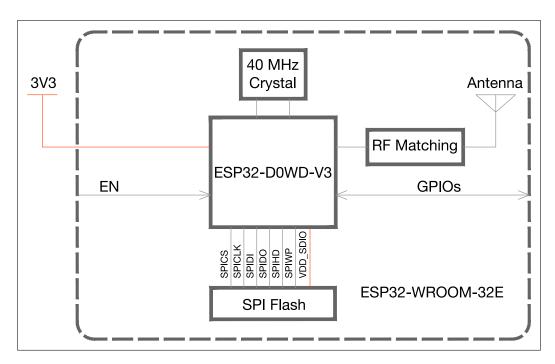


Figure 1: ESP32-WROOM-32E Block Diagram

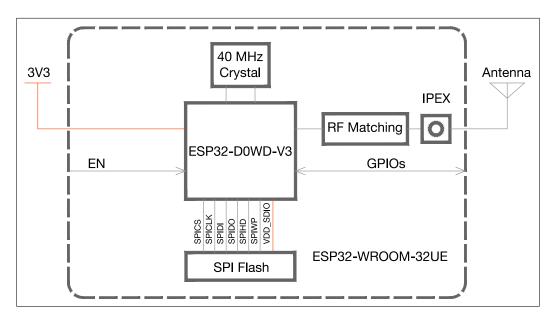


Figure 2: ESP32-WROOM-32UE Block Diagram

3 Pin Definitions

3.1 Pin Layout

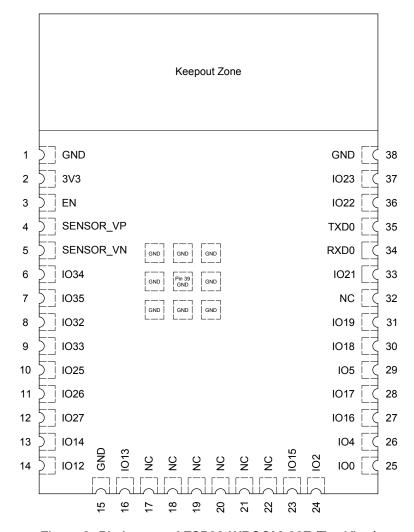


Figure 3: Pin Layout of ESP32-WROOM-32E (Top View)

Note:

- The pin layout of ESP32-WROOM-32UE is the same as that of ESP32-WROOM-32E, except that ESP32-WROOM-32UE has no keepout zone.
- The pin diagram shows the approximate location of pins on the module. For the actual mechanical diagram, please refer to Section 7.1 *Physical Dimensions*.

3.2 Pin Description

The module has 38 pins. See pin definitions in Table 2.

Table 2: Pin Definitions

GND	Name	No.	Туре	Function
High: On; enables the chip	GND	1	Р	Ground
EN	3V3	2	Р	Power supply
Note: Do not leave the pin floating. SENSOR_VP				High: On; enables the chip
SENSOR_VP	EN	3	I	Low: Off; the chip powers off
SENSOR_VN 5				Note: Do not leave the pin floating.
I	SENSOR_VP	4	1	GPIO36, ADC1_CH0, RTC_GPIO0
IO35	SENSOR_VN	5	I	GPIO39, ADC1_CH3, RTC_GPIO3
IO32	IO34	6	I	GPIO34, ADC1_CH6, RTC_GPIO4
1032	IO35	7	I	GPIO35, ADC1_CH7, RTC_GPIO5
TOUCH9, RTC_GPIO9	1000	0	1/0	GPIO32, XTAL_32K_P (32.768 kHz crystal oscillator input), ADC1_CH4,
1033 9 1/0 ADC1_CH5, TOUCH8, RTC_GPI08 1025 10 1/0 GPI025, DAC_1, ADC2_CH8, RTC_GPI06, EMAC_RXD0 1026 11 1/0 GPI026, DAC_2, ADC2_CH9, RTC_GPI07, EMAC_RXD1 1027 12 1/0 GPI027, ADC2_CH7, TOUCH7, RTC_GPI017, EMAC_RX_DV 1014 13 1/0 GPI014, ADC2_CH6, TOUCH6, RTC_GPI016, MTMS, HSPICLK, HS2_CLK, SD_CLK, EMAC_TXD2 1012 14 1/0 GPI012, ADC2_CH5, TOUCH5, RTC_GPI015, MTDI, HSPIQ, HS2_DATA2, SD_DATA2, EMAC_TXD3 15 P Ground 1013 16 1/0 GPI013, ADC2_CH4, TOUCH4, RTC_GPI014, MTCK, HSPID, HS2_DATA3, SD_DATA3, EMAC_RX_ER NC 17 See note 1 under the table. NC 18 See note 1 under the table. NC 19 See note 1 under the table. NC 20 See note 1 under the table. NC 21 See note 1 under the table. NC 22 GPI015, ADC2_CH3, TOUCH3, MTD0, HSPICS0, RTC_GPI013, HS2_CMD, SD_CMD, EMAC_RXD3 NO GPI02, ADC2_CH2, TOUCH2, RTC_GPI012, HSPIWP, HS2_DATA0, SD_DATA0 SD_DATA0 SD_DATA1, EMAC_TX_ER NO 26 1/0 GPI04, ADC2_CH0, TOUCH0, RTC_GPI010, HSPIHD, HS2_DATA1, SD_DATA1, EMAC_TX_ER NO GPI016, HS1_DATA4, U2RXD, EMAC_CLK_OUT_180 NO GPI017, HS1_DATA5, U2TXD, EMAC_CLK_OUT_180 NO GPI016, HS1_DATA5, U2TXD, EMAC_CLK_	1032	0	1/0	TOUCH9, RTC_GPIO9
ADC1_CH5, TOUCH8, RTC_GPIO8	1000	0	1/0	GPIO33, XTAL_32K_N (32.768 kHz crystal oscillator output),
1026	1033	9	1/0	ADC1_CH5, TOUCH8, RTC_GPIO8
12	IO25	10	I/O	GPIO25, DAC_1, ADC2_CH8, RTC_GPIO6, EMAC_RXD0
IO14	IO26	11	I/O	GPIO26, DAC_2, ADC2_CH9, RTC_GPIO7, EMAC_RXD1
13	1027	12	I/O	GPIO27, ADC2_CH7, TOUCH7, RTC_GPIO17, EMAC_RX_DV
HS2_CLK, SD_CLK, EMAC_TXD2 GPI012, ADC2_CH5, TOUCH5, RTC_GPI015, MTDI, HSPIQ, HS2_DATA2, SD_DATA2, EMAC_TXD3 GND	1014	10	1/0	GPIO14, ADC2_CH6, TOUCH6, RTC_GPIO16, MTMS, HSPICLK,
14	1014	13	1/0	HS2_CLK, SD_CLK, EMAC_TXD2
HS2_DATA2, SD_DATA2, EMAC_TXD3	1010	4.4	1/0	GPIO12, ADC2_CH5, TOUCH5, RTC_GPIO15, MTDI, HSPIQ,
IO13	1012	14	1/0	HS2_DATA2, SD_DATA2, EMAC_TXD3
NC	GND	15	Р	Ground
HS2_DATA3, SD_DATA3, EMAC_RX_ER	1010	16	1/0	GPIO13, ADC2_CH4, TOUCH4, RTC_GPIO14, MTCK, HSPID,
NC 18 - See note 1 under the table. NC 19 - See note 1 under the table. NC 20 - See note 1 under the table. NC 21 - See note 1 under the table. NC 22 - See note 1 under the table. IO15 23 I/O GPIO15, ADC2_CH3, TOUCH3, MTDO, HSPICSO, RTC_GPIO13, HS2_CMD, SD_CMD, EMAC_RXD3 IO2 24 I/O GPIO2, ADC2_CH2, TOUCH2, RTC_GPIO12, HSPIWP, HS2_DATA0, SD_DATA0 IO0 25 I/O GPIO0, ADC2_CH1, TOUCH1, RTC_GPIO11, CLK_OUT1, EMAC_TX_CLK IO4 26 I/O GPIO4, ADC2_CH0, TOUCH0, RTC_GPIO10, HSPIHD, HS2_DATA1, SD_DATA1, EMAC_TX_ER IO16 27 I/O GPIO16, HS1_DATA4, U2RXD, EMAC_CLK_OUT IO17 28 I/O GPIO17, HS1_DATA5, U2TXD, EMAC_CLK_OUT_180	1013	10	1/0	HS2_DATA3, SD_DATA3, EMAC_RX_ER
NC 19 - See note 1 under the table. NC 20 - See note 1 under the table. NC 21 - See note 1 under the table. NC 22 - See note 1 under the table. IO15 23 I/O GPIO15, ADC2_CH3, TOUCH3, MTDO, HSPICSO, RTC_GPIO13, HS2_CMD, SD_CMD, EMAC_RXD3 IO2 24 I/O GPIO2, ADC2_CH2, TOUCH2, RTC_GPIO12, HSPIWP, HS2_DATA0, SD_DATA0 IO0 25 I/O GPIO0, ADC2_CH1, TOUCH1, RTC_GPIO11, CLK_OUT1, EMAC_TX_CLK IO4 26 I/O GPIO4, ADC2_CH0, TOUCH0, RTC_GPIO10, HSPIHD, HS2_DATA1, SD_DATA1, EMAC_TX_ER IO16 27 I/O GPIO16, HS1_DATA4, U2RXD, EMAC_CLK_OUT IO17 28 I/O GPIO17, HS1_DATA5, U2TXD, EMAC_CLK_OUT_180	NC	17	-	See note 1 under the table.
NC 20 - See note 1 under the table. NC 21 - See note 1 under the table. NC 22 - See note 1 under the table. IO15 23 I/O GPIO15, ADC2_CH3, TOUCH3, MTDO, HSPICSO, RTC_GPIO13, HS2_CMD, SD_CMD, EMAC_RXD3 IO2 24 I/O GPIO2, ADC2_CH2, TOUCH2, RTC_GPIO12, HSPIWP, HS2_DATAO, SD_DATAO IO0 25 I/O GPIO0, ADC2_CH1, TOUCH1, RTC_GPIO11, CLK_OUT1, EMAC_TX_CLK IO4 26 I/O GPIO4, ADC2_CH0, TOUCH0, RTC_GPIO10, HSPIHD, HS2_DATA1, SD_DATA1, EMAC_TX_ER IO16 27 I/O GPIO16, HS1_DATA4, U2RXD, EMAC_CLK_OUT IO17 28 I/O GPIO17, HS1_DATA5, U2TXD, EMAC_CLK_OUT_180	NC	18	-	See note 1 under the table.
NC 21 - See note 1 under the table. NC 22 - See note 1 under the table. IO15 23 I/O GPIO15, ADC2_CH3, TOUCH3, MTDO, HSPICSO, RTC_GPIO13, HS2_CMD, SD_CMD, EMAC_RXD3 IO2 24 I/O GPIO2, ADC2_CH2, TOUCH2, RTC_GPIO12, HSPIWP, HS2_DATA0, SD_DATA0 IO0 25 I/O GPIO0, ADC2_CH1, TOUCH1, RTC_GPIO11, CLK_OUT1, EMAC_TX_CLK IO4 26 I/O GPIO4, ADC2_CH0, TOUCH0, RTC_GPIO10, HSPIHD, HS2_DATA1, SD_DATA1, EMAC_TX_ER IO16 27 I/O GPIO16, HS1_DATA4, U2RXD, EMAC_CLK_OUT IO17 28 I/O GPIO17, HS1_DATA5, U2TXD, EMAC_CLK_OUT_180	NC	19	-	See note 1 under the table.
NC 22 - See note 1 under the table. IO15 23 I/O GPIO15, ADC2_CH3, TOUCH3, MTDO, HSPICSO, RTC_GPIO13, HS2_CMD, SD_CMD, EMAC_RXD3 IO2 24 I/O GPIO2, ADC2_CH2, TOUCH2, RTC_GPIO12, HSPIWP, HS2_DATAO, SD_DATAO IO0 25 I/O GPIO0, ADC2_CH1, TOUCH1, RTC_GPIO11, CLK_OUT1, EMAC_TX_CLK IO4 26 I/O GPIO4, ADC2_CH0, TOUCH0, RTC_GPIO10, HSPIHD, HS2_DATA1, SD_DATA1, EMAC_TX_ER IO16 27 I/O GPIO16, HS1_DATA4, U2RXD, EMAC_CLK_OUT IO17 28 I/O GPIO17, HS1_DATA5, U2TXD, EMAC_CLK_OUT_180	NC	20	-	See note 1 under the table.
IO15	NC	21	-	See note 1 under the table.
1015 23 1/0 HS2_CMD, SD_CMD, EMAC_RXD3 102 24 1/0 GPIO2, ADC2_CH2, TOUCH2, RTC_GPIO12, HSPIWP, HS2_DATA0, SD_DATA0 100 25 1/0 GPIO0, ADC2_CH1, TOUCH1, RTC_GPIO11, CLK_OUT1, EMAC_TX_CLK 104 26 1/0 GPIO4, ADC2_CH0, TOUCH0, RTC_GPIO10, HSPIHD, HS2_DATA1, SD_DATA1, EMAC_TX_ER 1016 27 1/0 GPIO16, HS1_DATA4, U2RXD, EMAC_CLK_OUT 1017 28 1/0 GPIO17, HS1_DATA5, U2TXD, EMAC_CLK_OUT_180	NC	22	-	See note 1 under the table.
HS2_CMD, SD_CMD, EMAC_RXD3 IO2	1015	00	1/0	GPIO15, ADC2_CH3, TOUCH3, MTDO, HSPICS0, RTC_GPIO13,
102	1015	23	1/0	HS2_CMD, SD_CMD, EMAC_RXD3
SD_DATA0 SD_DATA0 SD_DATA0 GPIO0, ADC2_CH1, TOUCH1, RTC_GPIO11, CLK_OUT1, EMAC_TX_CLK GPIO4, ADC2_CH0, TOUCH0, RTC_GPIO10, HSPIHD, HS2_DATA1, SD_DATA1, EMAC_TX_ER IO16 27 I/O GPIO16, HS1_DATA4, U2RXD, EMAC_CLK_OUT IO17 28 I/O GPIO17, HS1_DATA5, U2TXD, EMAC_CLK_OUT_180	100	0.4	1/0	GPIO2, ADC2_CH2, TOUCH2, RTC_GPIO12, HSPIWP, HS2_DATA0,
100 25 1/0 EMAC_TX_CLK	102	24	1/0	SD_DATA0
EMAC_TX_CLK	100	0.5	1/0	GPIO0, ADC2_CH1, TOUCH1, RTC_GPIO11, CLK_OUT1,
IO4 26 I/O SD_DATA1, EMAC_TX_ER IO16 27 I/O GPIO16, HS1_DATA4, U2RXD, EMAC_CLK_OUT IO17 28 I/O GPIO17, HS1_DATA5, U2TXD, EMAC_CLK_OUT_180	100	25	1/0	EMAC_TX_CLK
SD_DATA1, EMAC_TX_ER	104	00	1/0	GPIO4, ADC2_CH0, TOUCH0, RTC_GPIO10, HSPIHD, HS2_DATA1,
IO17 28 I/O GPIO17, HS1_DATA5, U2TXD, EMAC_CLK_OUT_180	104	26	1/0	SD_DATA1, EMAC_TX_ER
	IO16	27	I/O	GPIO16, HS1_DATA4, U2RXD, EMAC_CLK_OUT
IOS DO NO ODIOS VODICOS LIST DATAS SAMO DV CITA	IO17	28	I/O	GPIO17, HS1_DATA5, U2TXD, EMAC_CLK_OUT_180
105 29 1/0 GM105, VSM1CSU, HST_DATA6, EMAC_KX_CLK	105	29	I/O	GPIO5, VSPICS0, HS1_DATA6, EMAC_RX_CLK
IO18 30 I/O GPIO18, VSPICLK, HS1_DATA7	IO18	30	I/O	GPIO18, VSPICLK, HS1_DATA7
IO19 31 I/O GPIO19, VSPIQ, U0CTS, EMAC_TXD0	IO19	31	I/O	GPIO19, VSPIQ, U0CTS, EMAC_TXD0

Name	No.	Туре	Function
NC	32	-	-
IO21	33	I/O	GPIO21, VSPIHD, EMAC_TX_EN
RXD0	34	I/O	GPIO3, U0RXD, CLK_OUT2
TXD0	35	I/O	GPIO1, U0TXD, CLK_OUT3, EMAC_RXD2
IO22	36	I/O	GPIO22, VSPIWP, UORTS, EMAC_TXD1
IO23	37	I/O	GPIO23, VSPID, HS1_STROBE
GND	38	Р	Ground

- 1. Pins GPIO6 to GPIO11 on the ESP32-D0WD-V3 chip are connected to the SPI flash integrated on the module and are not led out.
- 2. For peripheral pin configurations, please refer to ESP32 Datasheet.

3.3 Strapping Pins

ESP32 has five strapping pins: MTDI, GPIO0, GPIO2, MTDO, GPIO5. The pin-pin mapping between ESP32 and the module is as follows, which can be seen in Chapter 5 *Schematics*:

- MTDI = IO12
- GPIO0 = BOOT/IO0
- GPIO2 = IO2
- MTDO = IO15
- GPIO5 = IO5

Software can read the values of these five bits from register "GPIO_STRAPPING".

During the chip's system reset release (power-on-reset, RTC watchdog reset and brownout reset), the latches of the strapping pins sample the voltage level as strapping bits of "0" or "1", and hold these bits until the chip is powered down or shut down. The strapping bits configure the device's boot mode, the operating voltage of VDD_SDIO and other initial system settings.

Each strapping pin is connected to its internal pull-up/pull-down during the chip reset. Consequently, if a strapping pin is unconnected or the connected external circuit is high-impedance, the internal weak pull-up/pull-down will determine the default input level of the strapping pins.

To change the strapping bit values, users can apply the external pull-down/pull-up resistances, or use the host MCU's GPIOs to control the voltage level of these pins when powering on ESP32.

After reset release, the strapping pins work as normal-function pins.

Refer to Table 3 for a detailed boot-mode configuration by strapping pins.

Table 3: Strapping Pins

	Voltage of Internal LDO (VDD_SDIO)					
Pin Default 3.3 V 1.8 V						
MTDI	Pull-down	0	1			

	Booting Mode							
Pin	Default	SPL	Boot	Downlo	ad Boot			
GPI00	Pull-up	-	1	()			
GPIO2	Pull-down	Don't	-care	()			
Е	nabling/Disa	bling Debugging	g Log Print over	U0TXD During I	Booting			
Pin	Default	UOTXD	U0TXD Active U0TXD Silent					
MTDO	Pull-up	-	1	0				
		Timinç	g of SDIO Slave					
		FE Sampling	FE Sampling	RE Sampling	RE Sampling			
Pin	Default	FE Output	RE Output	FE Output RE Output				
MTDO	Pull-up	0	0	1 1				
GPIO5	Pull-up	0	1	0	1			

- FE: falling-edge, RE: rising-edge.
- Firmware can configure register bits to change the settings of "Voltage of Internal LDO (VDD_SDIO)" and "Timing of SDIO Slave", after booting.
- The module integrates a 3.3 V SPI flash, so the pin MTDI cannot be set to 1 when the module is powered up.

4 Electrical Characteristics

4.1 Absolute Maximum Ratings

Stresses beyond the absolute maximum ratings listed in the table below may cause permanent damage to the device. These are stress ratings only, and do not refer to the functional operation of the device that should follow the recommended operating conditions.

Table 4: Absolute Maximum Ratings

Symbol	Parameter	Min	Max	Unit
VDD33	Power supply voltage	-0.3	3.6	V
T_{STORE}	Storage temperature	-40	85	°C

Note:

Please see Appendix IO_MUX of <u>ESP32 Datasheet</u> for IO's power domain.

4.2 Recommended Operating Conditions

Table 5: Recommended Operating Conditions

Symbol	Parameter	Min	Тур	Max	Unit
VDD33	Power supply voltage	3.0	3.3	3.6	V
I_{VDD}	Current delivered by external power supply	0.5	_	_	А
Т	Operating temperature	-40	_	85	°C
Humidity	Humidity condition	_	85	_	%RH

4.3 DC Characteristics (3.3 V, 25 °C)

Table 6: DC Characteristics (3.3 V, 25 °C)

Symbol	Parameter	Min	Тур	Max	Unit
C_{IN}	Pin capacitance	-	2	-	рF
V_{IH}	High-level input voltage	0.75×VDD ¹	-	VDD1+0.3	V
V_{IL}	Low-level input voltage	-0.3	-	0.25×VDD ¹	V
$ I_{IH} $	High-level input current	-	-	50	nA
$ I_{IL} $	Low-level input current	-	-	50	nA
V_{OH}	High-level output voltage	0.8×VDD ¹	-	-	V
V_{OL}	Low-level output voltage	-	-	0.1×VDD ¹	V

Symbol	Parameter		Min	Тур	Max	Unit
	High-level source current (VDD 1 = 3.3 V, V _{OH} >= 2.64 V, output drive strength set to the maximum)	VDD3P3_CPU power domain ^{1, 2}	-	40	-	mA
I_{OH}		VDD3P3_RTC power domain ^{1, 2}	-	40	-	mA
		VDD_SDIO power domain ^{1, 3}	-	20	-	mA
I_{OL}	Low-level sink current (VDD 1 = 3.3 V, V $_{OL}$ = 0.495 V, output drive strength set to the maximum)		-	28	-	mA
R_{PU}	Resistance of internal pull-up resistor		-	45	-	kΩ
R_{PD}	Resistance of internal pull-down resistor		-	45	-	kΩ
V_{IL_nRST}	Low-level input voltage of CHIP_PU to power off the chip		-	_	0.6	V

- 1. Please see Appendix IO_MUX of <u>ESP32 Datasheet</u> for IO's power domain. VDD is the I/O voltage for a particular power domain of pins.
- 2. For VDD3P3_CPU and VDD3P3_RTC power domain, per-pin current sourced in the same domain is gradually reduced from around 40 mA to around 29 mA, $V_{OH}>=2.64$ V, as the number of current-source pins increases.
- 3. Pins occupied by flash and/or PSRAM in the VDD_SDIO power domain were excluded from the test.

4.4 Current Consumption Characteristics

With the use of advanced power-management technologies, ESP32 can switch between different power modes.

For details on ESP32's power consumption in different power modes, please refer to section "RTC and Low-Power Management" in *ESP32 Datasheet*.

4.4.1 Current Consumption Depending on RF Modes

Table 7: Current Consumption Depending on RF Modes

Work mode		Description	Average (mA)	Peak (mA)
	TX	802.11b, 20 MHz, 1 Mbps, @19.5 dBm		379
		802.11g, 20 MHz, 54 Mbps, @15 dBm	190	276
Active (RF working)		802.11b, 20 MHz, MCS7, @13 dBm	183	258
		802.11n, 40 MHz, MCS7, @13 dBm	165	211
	RX	802.11b/g/n	112	112
		802.11n, 40 MHz	118	118

- The current consumption measurements are taken with a 3.3 V supply at 25 °C of ambient temperature at the RF port. All transmitters' measurements are based on a 50% duty cycle.
- The current consumption figures for in RX mode are for cases when the peripherals are disabled and the CPU idle.

Wi-Fi RF Characteristics 4.5

4.5.1 Wi-Fi RF Standards

Table 8: Wi-Fi RF Standards

Name		Description		
Center frequency range of operating channel note1		2412 ~ 2484 MHz		
Wi-Fi wireless standard		IEEE 802.11b/g/n		
		11b: 1, 2, 5.5 and 11 Mbps		
Data rate	20 MHz	11g: 6, 9, 12, 18, 24, 36, 48, 54 Mbps		
Data rate		11n: MCS0-7, 72.2 Mbps (Max)		
	40 MHz	11n: MCS0-7, 150 Mbps (Max)		
Antenna type		PCB antenna, IPEX antenna		

Note:

- 1. Device should operate in the center frequency range allocated by regional regulatory authorities. Target center frequency range is configurable by software.
- 2. For the modules that use IPEX antennas, the output impedance is 50Ω . For other modules without IPEX antennas, users do not need to concern about the output impedance.

4.5.2 Transmitter Characteristics

Table 9: Transmitter Characteristics

Parameter	Rate	Тур	Unit
	11b, 1 Mbps	19.5	
	11b, 11 Mbps	19.5	
	11g, 6 Mbps	18	
TX Power note	11g, 54 Mbps	14	dBm
1 A Power	11n, HT20, MCS0	18	UDIII
	11n, HT20, MCS7	13	
	11n, HT40, MCS0	18	
	11n, HT40, MCS7	13	

Note:

Target TX power is configurable based on device or certification requirements.

4.5.3 Receiver Characteristics

Table 10: Receiver Characteristics

Parameter	Rate	Тур	Unit
RX Sensitivity	1 Mbps	-97	dBm
	2 Mbps	-94	
	5.5 Mbps	-92	
	11 Mbps	-88	
	6 Mbps	-93	
	9 Mbps	-91	
	12 Mbps	-89	
	18 Mbps	-87	
	24 Mbps	-84	
	36 Mbps	-80	
	48 Mbps	-77	
	54 Mbps	-75	
	11n, HT20, MCS0	-92	
	11n, HT20, MCS1	-88	
	11n, HT20, MCS2	-86	
	11n, HT20, MCS3	-83	
	11n, HT20, MCS4	-80	
	11n, HT20, MCS5	-76	
	11n, HT20, MCS6	-74	
	11n, HT20, MCS7	-72	
	11n, HT40, MCS0	-89	
	11n, HT40, MCS1	-85	
	11n, HT40, MCS2	-83	
	11n, HT40, MCS3	-80	
	11n, HT40, MCS4	-76	
	11n, HT40, MCS5	-72	
	11n, HT40, MCS6	-71	
	11n, HT40, MCS7	-69	
RX Maximum Input Level	11b, 1 Mbps	5	dBm
	11b, 11 Mbps	5	
	11g, 6 Mbps	0	
	11g, 54 Mbps	-8	
	11n, HT20, MCS0	0	
	11n, HT20, MCS7	-8	
	11n, HT40, MCS0	0	
	11n, HT40, MCS7	-8	
Adjacent Channel Rejection	11b, 11 Mbps	35	dB
	11g, 6 Mbps	27	
	11g, 54 Mbps	13	
	11n, HT20, MCS0	27	
	11n, HT20, MCS7	12	

Parameter	Rate	Тур	Unit
	11n, HT40, MCS0	16	
	11n, HT40, MCS7	7	

4.6 Bluetooth Radio

4.6.1 Receiver - Basic Data Rate

Table 11: Receiver Characteristics - Basic Data Rate

Parameter	Conditions	Min	Тур	Max	Unit
Sensitivity @0.1% BER	-	-90	-89	-88	dBm
Maximum received signal @0.1% BER	-	0	-	-	dBm
Co-channel C/I	-	-	+7	-	dB
Adjacent channel selectivity C/I	F = F0 + 1 MHz	-	-	-6	dB
	F = F0 – 1 MHz	-	-	-6	dB
Adjacent channel colectivity C/L	F = F0 + 2 MHz	-	-	-89 -88 +7 - 6 6	dB
Adjacent channel selectivity 0/1	F = F0 - 2 MHz	-	-		dB
	F = F0 + 3 MHz	-	-	-25	dB
Adjacent channel selectivity C/I	F = F0 - 3 MHz	-	-	-45	dB
	30 MHz ~ 2000 MHz	-10	-	-	dBm
Out-of-band blocking performance	2000 MHz ~ 2400 MHz	-27	-	-	dBm
Out-of-band blocking performance	2500 MHz ~ 3000 MHz	-27	-	-	dBm
	3000 MHz ~ 12.5 GHz	-10	-	-	dBm
Intermodulation	-	-36	-	_	dBm

4.6.2 Transmitter - Basic Data Rate

Table 12: Transmitter Characteristics - Basic Data Rate

Parameter	Conditions	Min	Тур	Max	Unit
RF transmit power (see note under Table 12)	-	-	0	-	dBm
Gain control step	-	-	3	-	dB
RF power control range	-	-12	-	+9	dBm
+20 dB bandwidth	-	-	0.9	-	MHz
	$F = F0 \pm 2 MHz$	-	-55	-	dBm
Adjacent channel transmit power	$F = F0 \pm 3 \text{ MHz}$	-	-55	-	dBm
	$F = F0 \pm > 3 MHz$	-	-59	-	dBm
$\Delta f1_{ ext{avg}}$	-	-	-	155	kHz
$\Delta f2_{\sf max}$	-	127	-	-	kHz
$\Delta f 2_{\text{avg}}/\Delta f 1_{\text{avg}}$	-	-	0.92	-	-
ICFT	-	-	-7	-	kHz
Drift rate	-	-	0.7	-	kHz/50 μ s
Drift (DH1)	-	-	6	-	kHz
Drift (DH5)	-	-	6	-	kHz

There are a total of eight power levels from 0 to 7, and the transmit power ranges from -12 dBm to 9 dBm. When the power level rises by 1, the transmit power increases by 3 dB. Power level 4 is used by default and the corresponding transmit power is 0 dBm.

4.6.3 Receiver - Enhanced Data Rate

Table 13: Receiver Characteristics - Enhanced Data Rate

Parameter	Conditions	Min	Тур	Max	Unit
$\pi/4$	DQPSK				
Sensitivity @0.01% BER	-	-90	-89	-88	dBm
Maximum received signal @0.01% BER	-	-	0	-	dBm
Co-channel C/I	-	-	11	-	dB
	F = F0 + 1 MHz	-	-7	-	dB
	PSK909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090909090	-	-7	-	dB
Adjacent channel colectivity C/I	F = F0 + 2 MHz	-	-25	-	dB
Adjacent channel selectivity C/I	F = F0 - 2 MHz	-	-35	-	dB
	F = F0 + 3 MHz	-	-25	-	dB
	F = F0 - 3 MHz	-	-45	-	dB
8	DPSK				
Sensitivity @0.01% BER	-	-84	-83	-82	dBm
Maximum received signal @0.01% BER	-	-	-5	-	dBm
C/I c-channel	-	-	18	-	dB
	F = F0 + 1 MHz	-	2	9 -88 0 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 -	dB
Sensitivity @0.01% BER Maximum received signal @0.01% BER	F = F0 - 1 MHz	-	2	-	dB
Adjacent channel colectivity C/I	F = F0 + 2 MHz	-	-25	3 -82 5 - 3 - 5 - 5 - 5 - 5 - 5 - 5 - 7 - 7 - 7 - 7 - 7 - 7 - 7 - 7 - 7 - 7	dB
π/4 Sensitivity @0.01% BER Maximum received signal @0.01% BER Co-channel C/I Adjacent channel selectivity C/I 80 Sensitivity @0.01% BER Maximum received signal @0.01% BER	F = F0 - 2 MHz	-	-25	-	dB
	F = F0 + 3 MHz	-	-25	-	dB
	F = F0 - 3 MHz	-	-38	-	dB

4.6.4 Transmitter - Enhanced Data Rate

Table 14: Transmitter Characteristics - Enhanced Data Rate

Parameter	Conditions	Min	Тур	Max	Unit
RF transmit power (see note under Table 12)	-	-	0	-	dBm
Gain control step	-	-	3	1	dB
RF power control range	-	-12	-	+9	dBm
$\pi/4$ DQPSK max w0	-	-	-0.72	1	kHz
$\pi/4$ DQPSK max wi	-	-	-6	1	kHz
$\pi/4$ DQPSK max lwi + w0l	-	-	-7.42	1	kHz
8DPSK max w0	-	-	0.7	1	kHz
8DPSK max wi	-	-	-9.6	1	kHz
8DPSK max lwi + w0l	-	-	-10	1	kHz

Parameter	Conditions	Min	Тур	Max	Unit
π/4 DQPSK modulation accuracy B DPSK modulation accuracy n-band spurious emissions	RMS DEVM	-	4.28	-	%
$\pi/4$ DQPSK modulation accuracy	99% DEVM	-	100	-	%
	Peak DEVM	-	13.3	-	%
8 DPSK modulation accuracy	RMS DEVM	-	5.8	-	%
8 DPSK modulation accuracy	99% DEVM	-	100	-	%
	Peak DEVM	-	14	1	%
8 DPSK modulation accuracy In-band spurious emissions	$F = F0 \pm 1 MHz$	-	-46	-	dBm
	$F = F0 \pm 2 MHz$	-	-44	-	dBm
III-barid spurious erriissions	$F = F0 \pm 3 \text{ MHz}$	-	-49	-	dBm
	F = F0 + /- > 3 MHz	-	-	-53	dBm
EDR differential phase coding	-	-	100	-	%

4.7 Bluetooth LE Radio

4.7.1 Receiver

Table 15: Receiver Characteristics - BLE

Parameter	Conditions	Min	Тур	Max	Unit
Sensitivity @30.8% PER	-	-94	-93	-92	dBm
Maximum received signal @30.8% PER	-	0	-	-	dBm
Co-channel C/I	-	-	+10	-	dB
	F = F0 + 1 MHz	-	-5	-	dB
	F = F0 - 1 MHz	-94 -93 -92 0 +10 - - +10 - 5 - 5 - 25 - 25 - 25 - MHz -10 - 0 MHz -27 - 0 MHz -27 -	dB		
Adjacent channel selectivity C/I	F = F0 + 2 MHz	-	-25	-92 - - - - - - - -	dB
Adjacent charmer selectivity C/1	F = F0 - 2 MHz	-	-35		dB
	F = F0 + 3 MHz	-	-25	-	dB
	F = F0 - 3 MHz	-	-45	-	dB
	30 MHz ~ 2000 MHz	-10	-93 - +10 -5 -5 -25 -35 -25	-	dBm
Out of hand blooking porformance	2000 MHz ~ 2400 MHz	-27	-	-	dBm
Out-or-band blocking performance	2500 MHz ~ 3000 MHz	-27	-94 -93 -92 0 +1055252545 102710	-	dBm
ensitivity @30.8% PER flaximum received signal @30.8% PER co-channel C/I djacent channel selectivity C/I out-of-band blocking performance	3000 MHz ~ 12.5 GHz	-10	-	-	dBm
Intermodulation	-	-36	-	-	dBm

4.7.2 Transmitter

Table 16: Transmitter Characteristics - BLE

Parameter	Conditions	Min	Тур	Max	Unit
RF transmit power (see note under Table 12)	-	-	0	-	dBm
Gain control step	-	-	3	-	dB
RF power control range	-	-12	-	+9	dBm
	$F = F0 \pm 2 MHz$	-	-55	-	dBm
Adjacent channel transmit power	$F = F0 \pm 3 \text{ MHz}$	-	-57	-	dBm

Parameter	Conditions	Min	Тур	Max	Unit
	$F = F0 \pm > 3 MHz$	-	-59	-	dBm
$\Delta f 1_{ ext{avg}}$	-	-	-	265	kHz
$\Delta~f2_{ ext{max}}$	-	210	-	-	kHz
$\Delta~f2_{ m avg}/\Delta~f1_{ m avg}$	-	-	+0.92	-	-
ICFT	-	-	-10	-	kHz
Drift rate	-	-	0.7	-	kHz/50 μs
Drift	-	-	2	ı	kHz

5 Schematics

This is the reference design of the module.

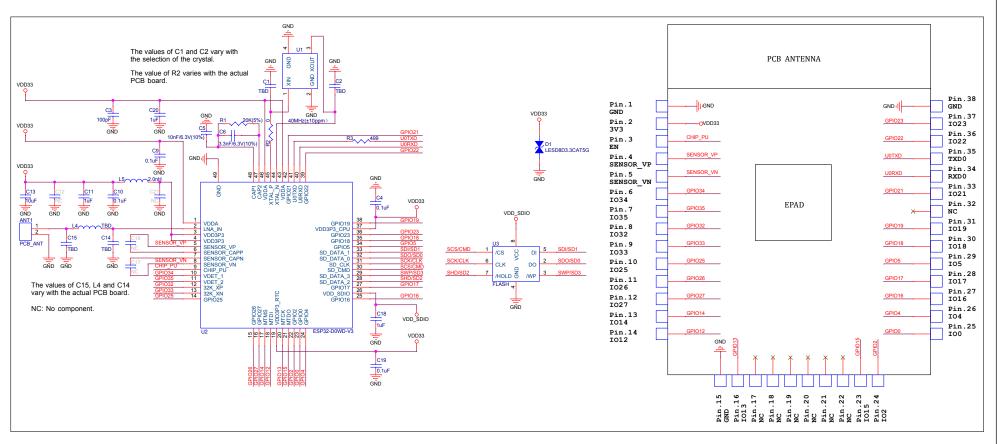


Figure 4: ESP32-WROOM-32E Schematics

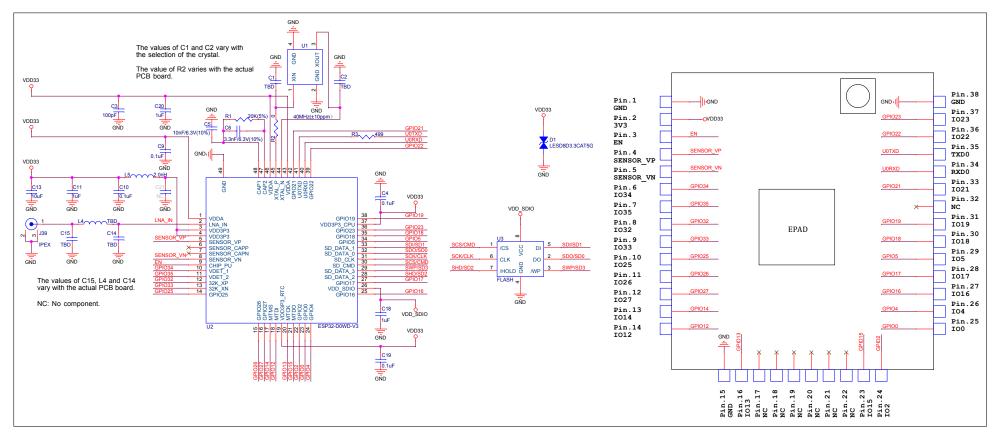


Figure 5: ESP32-WROOM-32UE Schematics

6 Peripheral Schematics

This is the typical application circuit of the module connected with peripheral components (for example, power supply, antenna, reset button, JTAG interface, and UART interface).

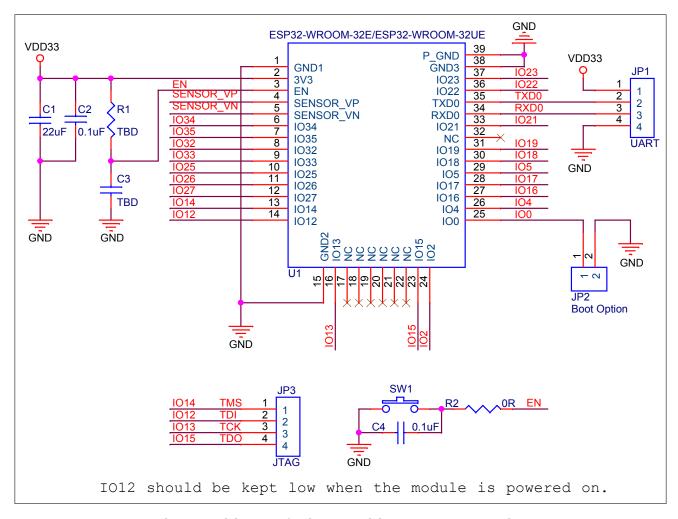


Figure 6: ESP32-WROOM-32E & ESP32-WROOM-32UE Peripheral Schematics

Note:

- Soldering Pad 39 to the Ground of the base board is not necessary for a satisfactory thermal performance. If users do want to solder it, they need to ensure that the correct quantity of soldering paste is applied.
- To ensure the power supply to the ESP32 chip during power-up, it is advised to add an RC delay circuit at the EN pin. The recommended setting for the RC delay circuit is usually R = 10 k Ω and C = 1 μ F. However, specific parameters should be adjusted based on the power-up timing of the module and the power-up and reset sequence timing of the chip. For ESP32's power-up and reset sequence timing diagram, please refer to Section *Power Scheme* in *ESP32 Datasheet*.

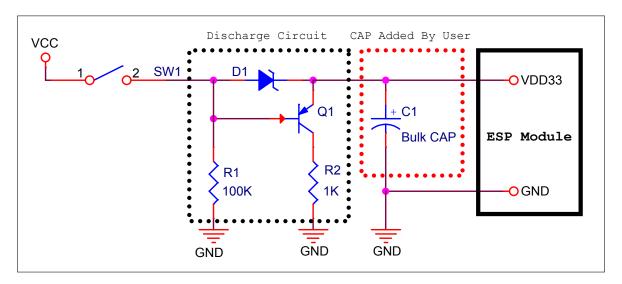


Figure 7: Discharge Circuit for VDD33 Rail

The discharge circuit can be applied in scenarios where ESP32 is powered on and off repeatedly by switching the power rails, and there is a large capacitor on the VDD33 rail. For details, please refer to Section *Power Scheme* in *ESP32 Datasheet*.

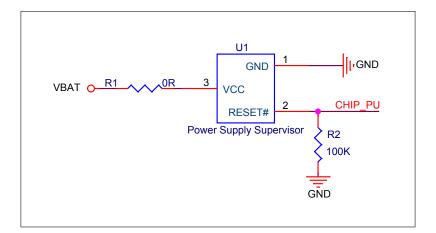


Figure 8: Reset Circuit

Note:

When battery is used as the power supply for ESP32 series of chips and modules, a supply voltage supervisor is recommended to avoid boot failure due to low voltage. Users are recommended to pull CHIP_PU low if the power supply for ESP32 is below 2.3 V.

7 Physical Dimensions and PCB Layout

7.1 Physical Dimensions

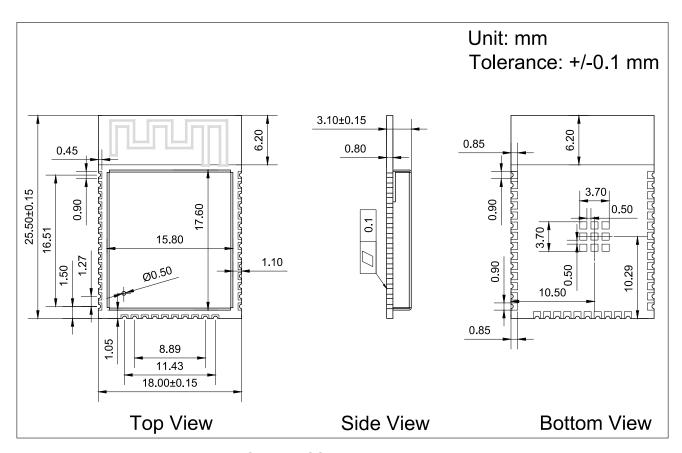


Figure 9: ESP32-WROOM-32E Physical Dimensions

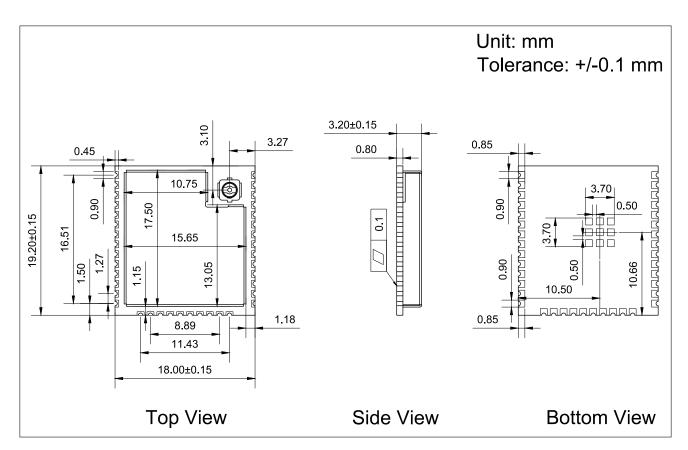


Figure 10: ESP32-WROOM-32UE Physical Dimensions

7.2 Recommended PCB Land Pattern

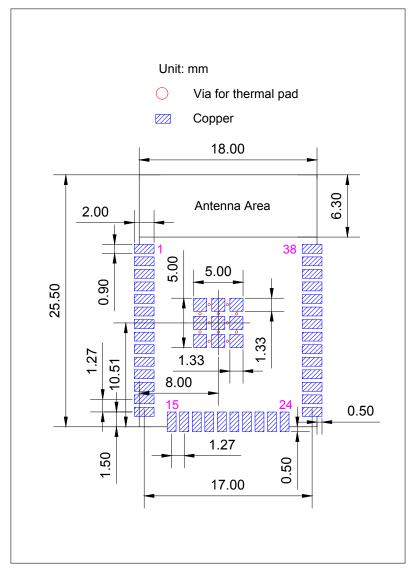


Figure 11: ESP32-WROOM-32E Recommended PCB Land Pattern

Note:

Location and pattern of thermal pad is designed for compatibility with former ESP32-WROVER and ESP32-WROVER-B modules and has wider area and bigger pad size than on the modules. Space on the landing pattern between the pads should be covered with solder mask.

For more information on the pad design, please refer to ESP32 Hardware Design Guidelines.

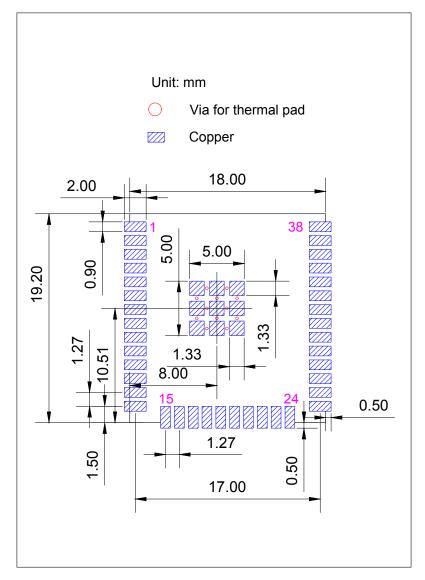


Figure 12: ESP32-WROOM-32UE Recommended PCB Land Pattern

Location and pattern of thermal pad is designed for compatibility with former ESP32-WROVER and ESP32-WROVER-B modules and has wider area and bigger pad size than on the modules. Space on the landing pattern between the pads should be covered with solder mask.

For more information on the pad design, please refer to *ESP32 Hardware Design Guidelines*.

7.3 U.FL Connector Dimensions

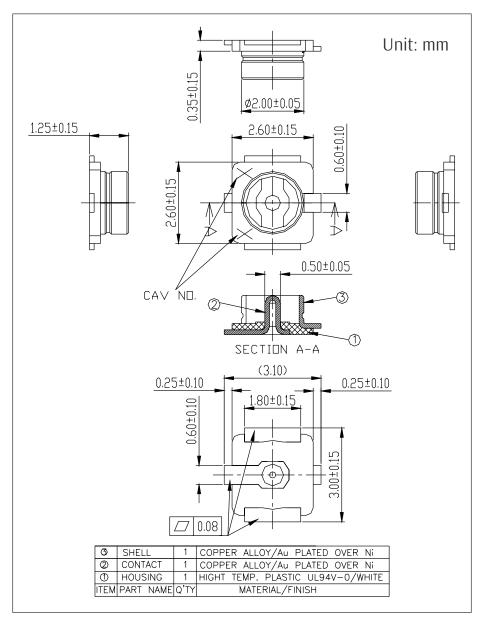


Figure 13: U.FL Connector Dimensions

8 Product Handling

8.1 Storage Condition

The products sealed in Moisture Barrier Bag (MBB) should be stored in a noncondensing atmospheric environment of < 40 °C/90% RH.

The module is rated at moisture sensitivity level (MSL) 3.

After unpacking, the module must be soldered within 168 hours with factory conditions 25±5 °C and 60% RH. The module needs to be baked if the above conditions are not met.

8.2 ESD

• Human body model (HBM): 2000 V

• Charged-device model (CDM): 500 V

• Air discharge: 6000 V

• Contact discharge: 4000 V

8.3 Reflow Profile

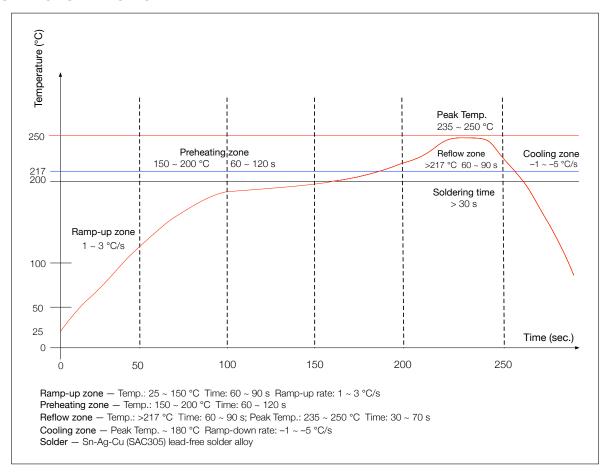


Figure 14: Reflow Profile

Note:

Solder the module in a single reflow. If the PCBA requires multiple reflows, place the module on the PCB during the final reflow.

9 MAC Addresses and eFuse

The eFuse in ESP32 has been burnt into 48-bit mac_address. The actual addresses the chip uses in station, AP, BLE, and Ethernet modes correspond to mac_address in the following way:

• Station mode: mac_address

• AP mode: mac_address + 1

• BLE mode: mac_address + 2

• Ethernet mode: mac_address + 3

In the 1 Kbit eFuse, 256 bits are used for the system (MAC address and chip configuration) and the remaining 768 bits are reserved for customer applications, including flash-encryption and chip-ID.

10 Learning Resources

10.1 Must-Read Documents

The following link provides documents related to ESP32.

• ESP32 Datasheet

This document provides an introduction to the specifications of the ESP32 hardware, including overview, pin definitions, functional description, peripheral interface, electrical characteristics, etc.

• ESP32 ECO V3 User Guide

This document describes differences between V3 and previous ESP32 silicon wafer revisions.

• ECO and Workarounds for Bugs in ESP32

This document details hardware errata and workarounds in the ESP32.

• ESP-IDF Programming Guide

It hosts extensive documentation for ESP-IDF ranging from hardware guides to API reference.

• ESP32 Technical Reference Manual

The manual provides detailed information on how to use the ESP32 memory and peripherals.

• ESP32 Hardware Resources

The zip files include the schematics, PCB layout, Gerber and BOM list of ESP32 modules and development boards.

• ESP32 Hardware Design Guidelines

The guidelines outline recommended design practices when developing standalone or add-on systems based on the ESP32 series of products, including the ESP32 chip, the ESP32 modules and development boards.

ESP32 AT Instruction Set and Examples

This document introduces the ESP32 AT commands, explains how to use them, and provides examples of several common AT commands.

• Espressif Products Ordering Information

10.2 Must-Have Resources

Here are the ESP32-related must-have resources.

• ESP32 BBS

This is an Engineer-to-Engineer (E2E) Community for ESP32 where you can post questions, share knowledge, explore ideas, and help solve problems with fellow engineers.

• ESP32 GitHub

ESP32 development projects are freely distributed under Espressif's MIT license on GitHub. It is established to help developers get started with ESP32 and foster innovation and the growth of general knowledge about the hardware and software surrounding ESP32 devices.

• ESP32 Tools

This is a webpage where users can download ESP32 Flash Download Tools and the zip file "ESP32 Certification and Test".

• ESP-IDF

This webpage links users to the official IoT development framework for ESP32.

• ESP32 Resources

This webpage provides the links to all available ESP32 documents, SDK and tools.

Revision History

Date	Version	Release notes
2020-11-02 V1.1	\/1 1	Added a note to EPAD in Section 7.2 Recommended PCB Land Pattern.
	V 1. 1	Updated the note to RC circuit in Section 6 Peripheral Schematics.
2020-05-29	V1.0	Official release.
2020-05-18	V0.5	Preliminary release.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Espressif:

ESP32-WROOM-32E(M113EH2800PH3Q0) ESP32-WROOM-32UE(M113EH2800UH3Q0) ESP32-WROOM-32UE(M113EH3200UH3Q0) ESP32-WROOM-32UE(M113EH6400UH3Q0) ESP32-WROOM-32UE(M113EH3200PH3Q0) ESP32-WROOM-32UE(M113EH6400PH3Q0) ESP32-WROOM-32UE(M113EH3200US3Q0)